NSN 5961-00-410-5439

Unitized Semiconductor Device Rectifier - Page 1 of 1



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Special Features:

A503j0

Four diffused silicon diodes interconnected in a transfer-molded plastic encapsulated case, 0.880 in. Min Ig, 0.920 in. Maximum Ig, 0.715 in. Min. W, 0.755 in. Maximum w, 0.240 in. Min h, 0.280 in. Maximum h, four ribbon type terminals spaced 0.180 in. Min to 0.220 in. Maximum c to c, one centrally located mtg hole through top of case to bottom of case, mtg hole 0.143 in. Min to 0.146 in. Maximum dia., m65 to p150 degrees c operating temp, 50v peak reverse voltage per cell, 35 v sine wave rms input voltage; storage temp range: minus 65.0 to 150 degrees celsius; unpackage weight: 7.500 grams

degrees ceisius, unpackage weight. 7.500 grams
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig: